

15A, 1000V Hyperfast Diode

The RHRP15100 is a hyperfast diode with soft recovery characteristics ($t_{rr} < 60\text{ns}$). It has half the recovery time of ultrafast diodes and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49062.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRP15100	TO-220AC	RHR15100

NOTE: When ordering, use the entire part number.

Symbol



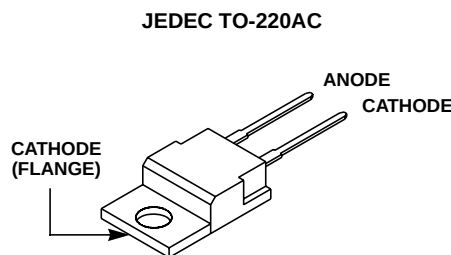
Features

- Hyperfast with Soft Recovery <60ns
- Operating Temperature 175°C
- Reverse Voltage 1000V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

	RHRP15100	UNITS
Peak Repetitive Reverse Voltage V_{RRM}	1000	V
Working Peak Reverse Voltage V_{RWM}	1000	V
DC Blocking Voltage V_R	1000	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_C = 130^\circ\text{C}$)	15	A
Repetitive Peak Surge Current I_{FRM} (Square Wave, 20kHz)	30	A
Nonrepetitive Peak Surge Current I_{FSM} (Halfwave, 1 Phase, 60Hz)	200	A
Maximum Power Dissipation P_D	100	W
Avalanche Energy (See Figures 10 and 11) E_{AVL}	20	mJ
Operating and Storage Temperature T_{STG}, T_J	-65 to 175	°C

Electrical Specifications $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V_F	$I_F = 15\text{A}$	-	-	3.0	V
	$I_F = 15\text{A}$, $T_C = 150^\circ\text{C}$	-	-	2.5	V
I_R	$V_R = 1000\text{V}$	-	-	100	μA
	$V_R = 1000\text{V}$, $T_C = 150^\circ\text{C}$	-	-	500	μA
t_{rr}	$I_F = 1\text{A}$, $dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	60	ns
	$I_F = 15\text{A}$, $dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	70	ns
t_a	$I_F = 15\text{A}$, $dI_F/dt = 100\text{A}/\mu\text{s}$	-	40	-	ns
t_b	$I_F = 15\text{A}$, $dI_F/dt = 100\text{A}/\mu\text{s}$	-	25	-	ns
Q_{RR}	$I_F = 15\text{A}$, $dI_F/dt = 100\text{A}/\mu\text{s}$	-	160	-	nC
C_J	$V_R = 10\text{V}$, $I_F = 0\text{A}$	-	66	-	pF
$R_{\theta JC}$		-	-	1.5	$^\circ\text{C}/\text{W}$

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs , D = 2%).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time (Figure 9), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

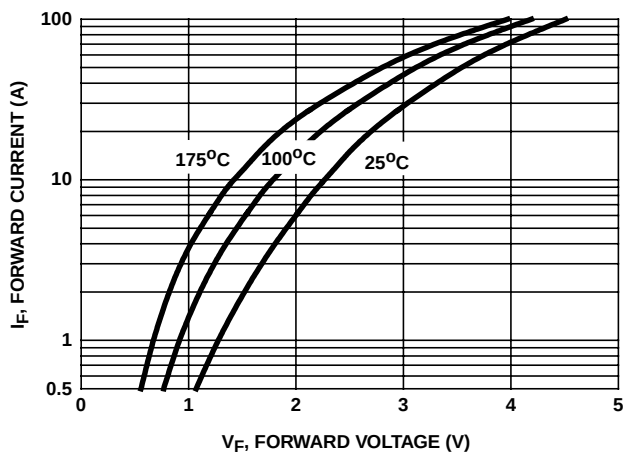


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

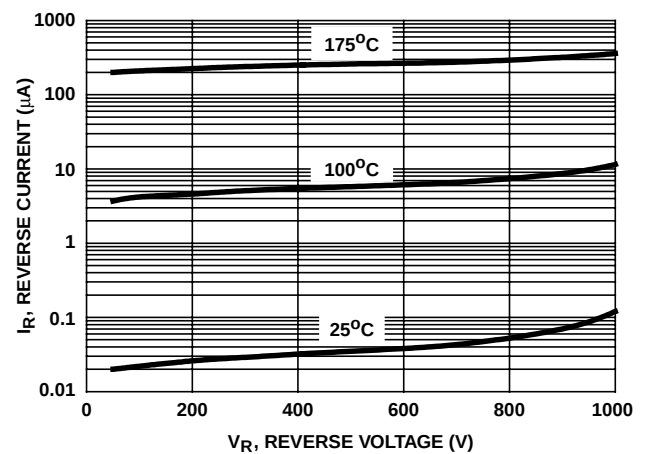


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

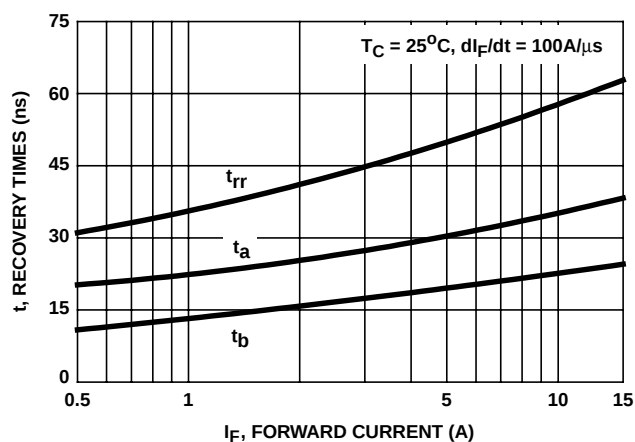
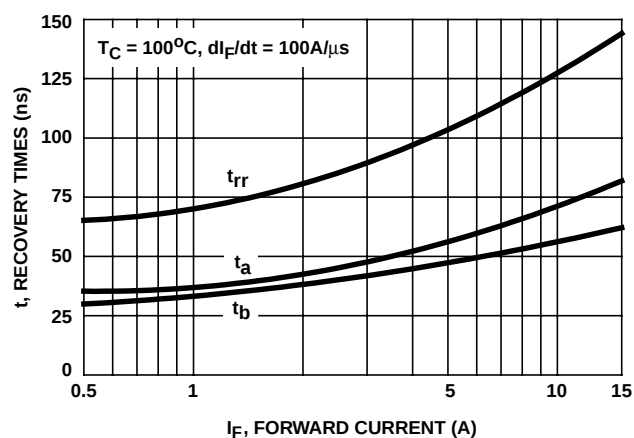
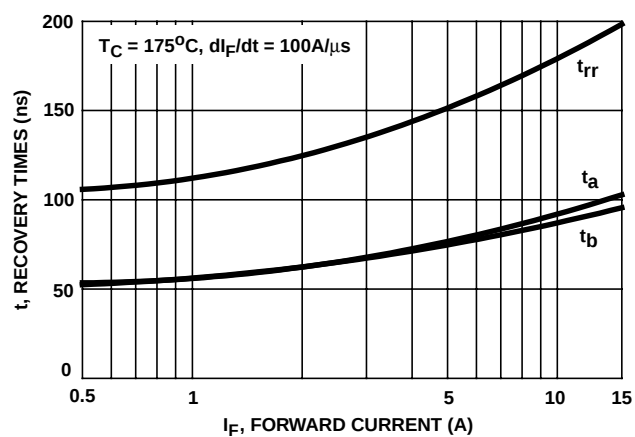
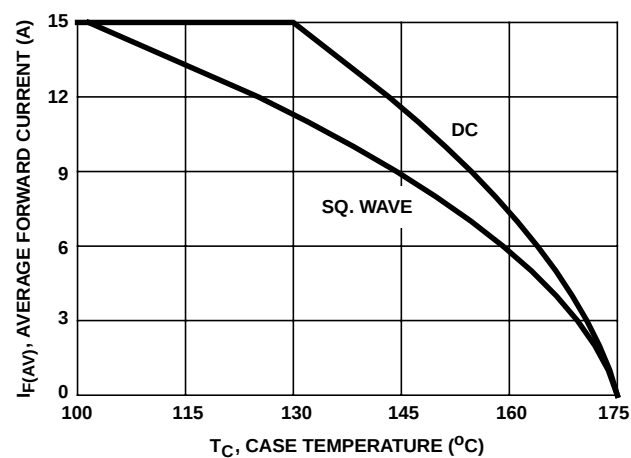
FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENTFIGURE 4. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENTFIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

FIGURE 6. CURRENT DERATING CURVE

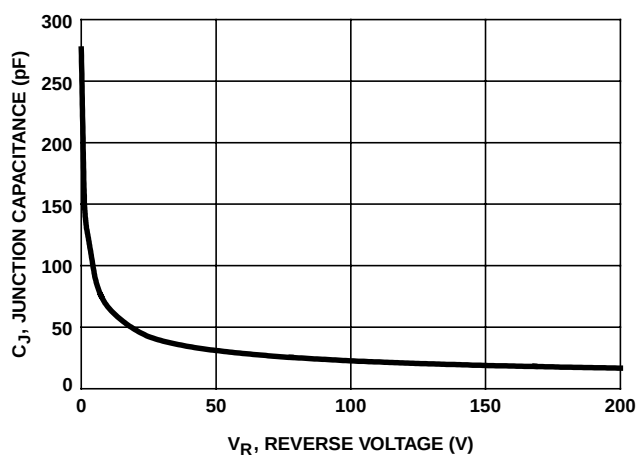


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

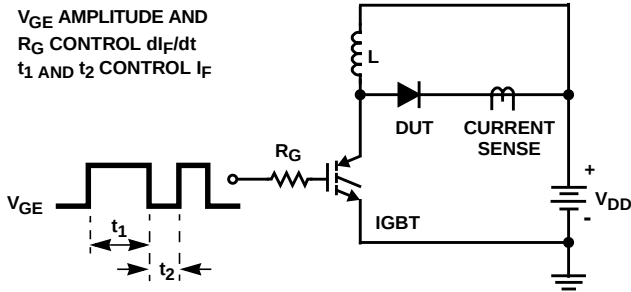
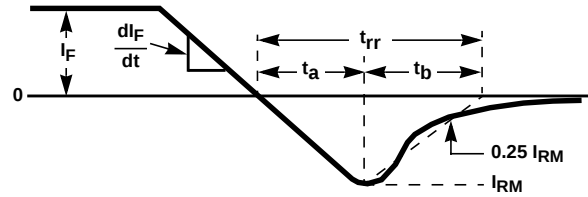
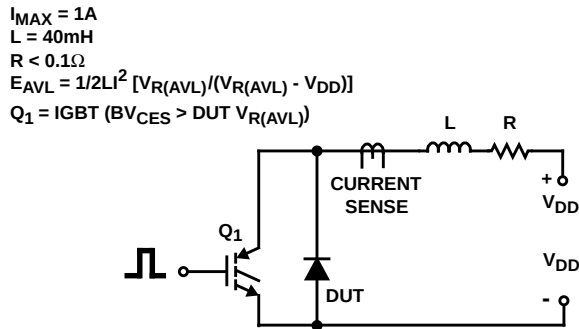
FIGURE 8. t_{rr} TEST CIRCUITFIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

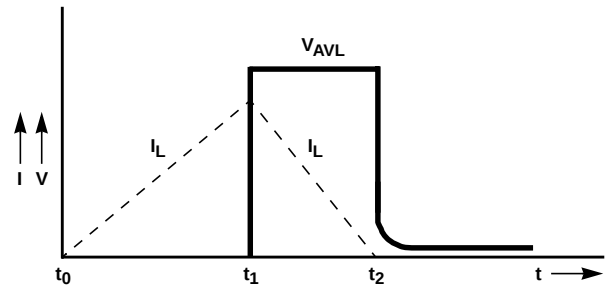


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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